# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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SEMICONDUCTOR

# 2N5638

### **N-Channel Switch**

- This device is designed for low level analog switchng, sample and hold circuits and chopper stabilized amplifiers.
- Sourced from process 51.



1. Drain 2. Source 3. Gate

## Absolute Maximum Ratings \* T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>DG</sub>	Drain-Gate Voltage	30	V
V <sub>GS</sub>	Gate-Source Voltage	-30	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

These ratings are based on a maximum junction temperature of 150 degrees C.
These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

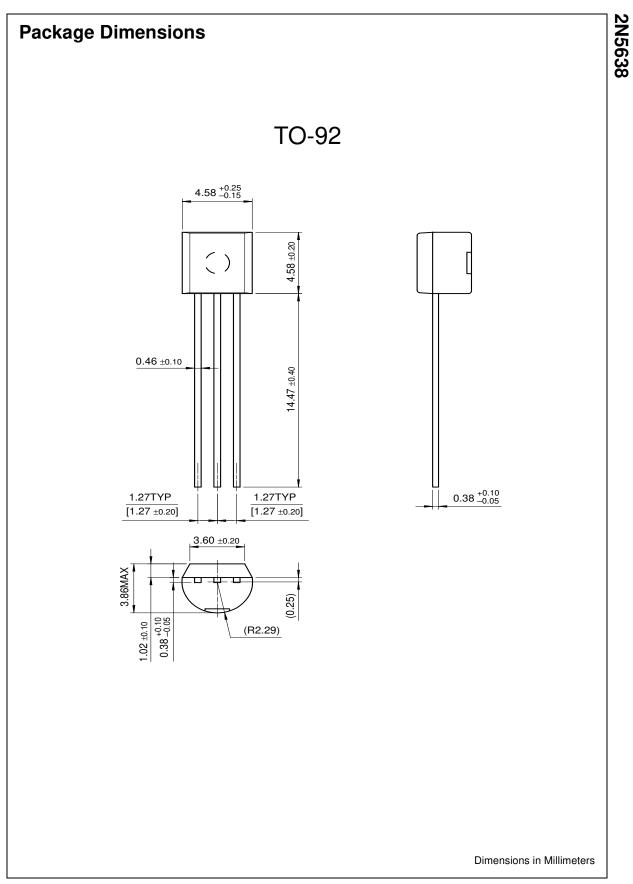
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	cteristics	·			•	
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_{G} = -10\mu A$	-30			V
I <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = -15V, V_{DS} = 0$			-1.0	nA
I <sub>D(off)</sub>	Drain Cutoff Leakage Current	V <sub>DS</sub> = 12V, V <sub>GS</sub> = 15V			1.0	nA
On Chara	cteristics					
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current *	$V_{DS} = 20V, I_{GS} = 0$	50			mA
r <sub>DS(on)</sub>	Drain-Source On Resistance	$V_{GS} = 0V, I_{D} = 1.0mA$			30	Ω
Small Sig	nal Characteristics					
r <sub>ds(on)</sub>	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0, f = 1.0 kHz$			30	Ω
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> = 0, V <sub>GS</sub> = 12V, f = 1.0MHz			10	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 12V, f = 1.0MHz			4.0	pF
Switching	Characteristics					
t <sub>d(on)</sub>	Trun On Delay Time	$V_{DD} = 10V, V_{GS(on)} = 0$			4.0	ns
t <sub>r</sub>	Rise Time	$V_{GS(off)} = -12, I_{D(on)} = 12mA$			5.0	ns
t <sub>d(off)</sub>	Trun Off Delay Time	$R_{G} = 50\Omega$		İ.	5.0	ns
t <sub>f</sub>	Fall Time			1	10	ns

\* Pulse Test: Pulse Width  $\leq 300 \mu s, \, Duty \, Cycle \leq 1.0\%$ 

#### Thermal Characteristics T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Max.	Units	
PD	Total Device Dissipation	350	mW	
-	Derate above 25°C	2.8	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W	

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Datasheet Identification	Product Status	Definition
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